**UNIVERSIDAD CARLOS III DE MADRID** 



## Analog integrated circuits design exercises

## Integrated Circuits and Microelectronics

Luis Entrena

Celia López

Marta Portela

Almudena Lindoso

Mario García

Enrique San Millán

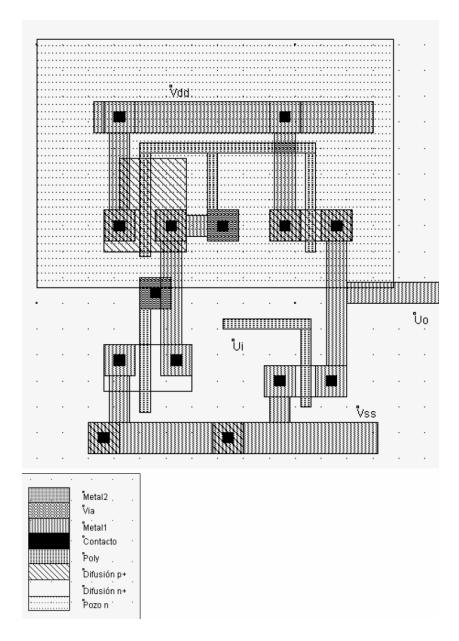
## Exercise 1

The figure shows the physical scheme of an amplifier stage.

- a) Draw the transistor scheme and indicate the aspect ratio W/L for each transistor.
- b) Calculate the drain current through each transistor
- c) Obtain Vo/Vi the amplifier gain

Data:

$$\begin{split} k_n &= \mu_n \, C_{ox} = 120 \; \mu A/V_2 \\ k_p &= \mu_p \, C_{ox} = 50 \; \mu A/V_2 \\ \lambda_n &= \lambda_p = 0.1 \; V_{-1} \\ |V_{tn}| &= |V_{tp}| = 1 V \\ V_{dd} &= 5 \; V \\ V_{ss} &= 0 \; V \end{split}$$

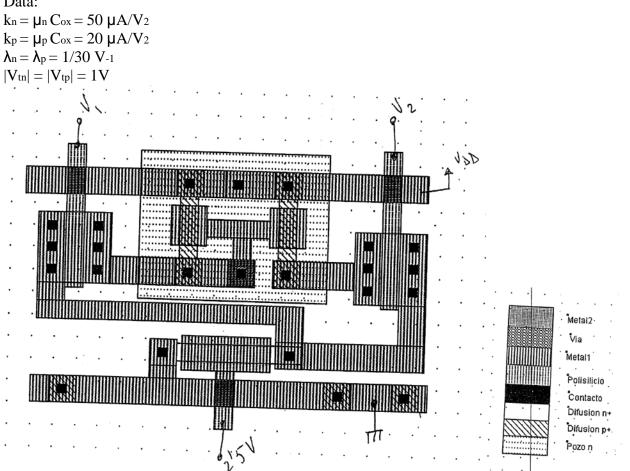


Exercise 2

The figure shows the physical scheme of an amplifier of two stages.

- a) Draw the transistor scheme and indicate the aspect ratio W/L for each transistor.
- b) Calculate the drain current through each transistor and the current supplied by the source at a
- c) Obtain Vo/Vi the amplifier gain

Data:



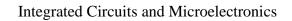
## **Exercise 3**

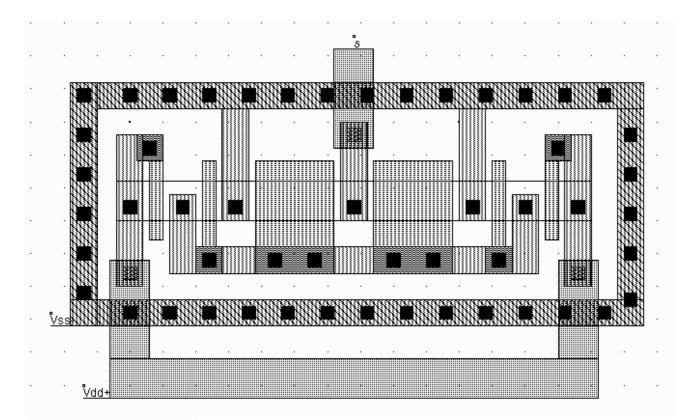
The figure shows the physical scheme of an analog circuit.

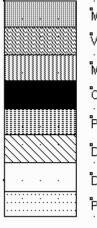
- a) Draw the transistor scheme and indicate the aspect ratio W/L for each transistor.
- b) Which is the purpose of so many contacts around the circuit?
- c) Obtain the voltage at A and the current through each transistor

Data:

 $k_n = \mu_n C_{ox} = 120 \ \mu A/V_2$  $k_p = \mu_p C_{ox} = 50 \ \mu A/V_2$  $\lambda_n = \lambda_p = 0.1 \text{ V}_{-1}$  $|V_{tn}| = |V_{tp}| = 1V$ Vdd=5V Vss=0V







Metal2. Via Metal1. Contacto Poly Difusión p+

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- Difusión n+
- Pozo n